# Polarized Source Development Activities at Hiroshima

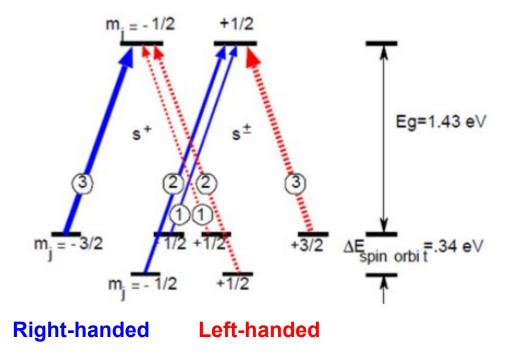
Zachary Liptak\* 5/28/2020

\*: with significant material from M. Kuriki

# Cathode Development

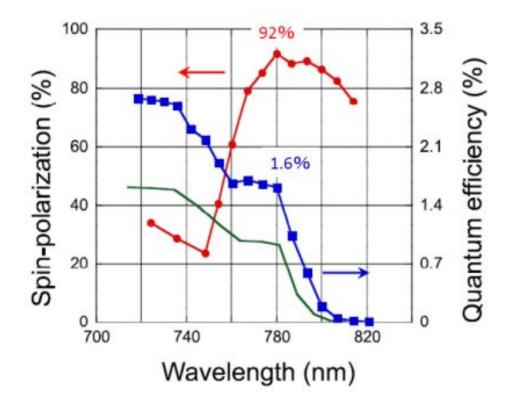
- HU Accelerator group (M. Kuriki + grad students, now myself) working on developing backup polarized source for ILC.
- Current focus is on GaAs cathode with a thin Negative Electron Affinity (NEA) surface.

# Generating a polarized beam



- Electrons are excited with a laser
- Using a circularly polarized laser produces polarized excited electrons

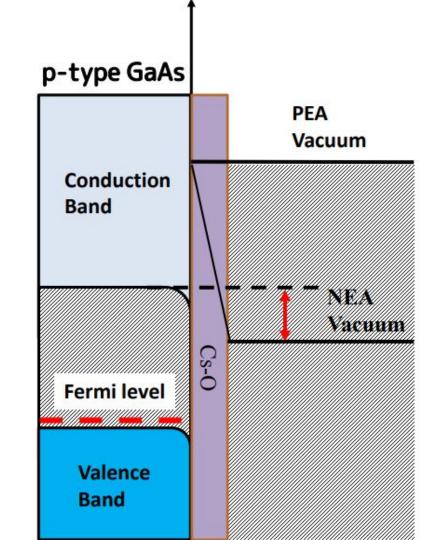
# Polarization and Q\_eff



 Polarization up to 92% has been achieved with a QE of 1.6% from GaAs.

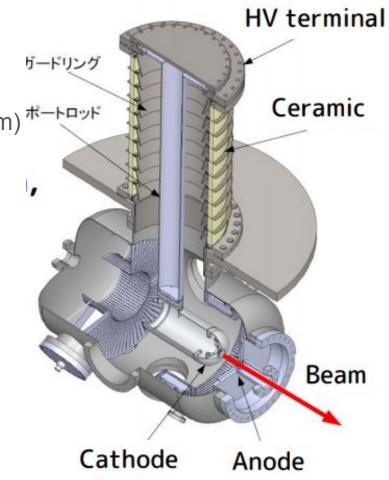
# **Negative Electron Affinity**

- Electrons excited to conduction band in GaAs bulk have very little momentum.
- NEA surface with a lower CB bottom can be applied to the cathode surface to make it easier to extract and accelerate electrons.



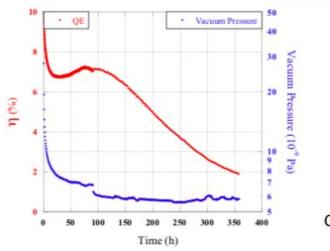
# **Electron Extraction**

- RF Gun has a high gradient ( up to 100 MV/m) <sup>#-トロッド</sup> but vacuum is insufficent and GaAs + NEA lifetime is too short
- Use DC bias instead
  - Limited field: ~ 10 MV/m max
- Beam density is limited → need buncher to achieve high bunch density



#### Improving lifetimes of NEA surfaces

- Current NEA surfaces made of Cs-O
  - Require UHV (  $< 10^{-9}$  Pa)
  - Limited bunch intensity, long bunches and large emittance
- Working on developing more robust NEA surface: Cs-K-Te



#### 1/e lifetime 3.0 – 4.0 x 10<sup>-4</sup> Pa.sec

C. Shonaka, Master thesis, Hiroshima U. (2009)

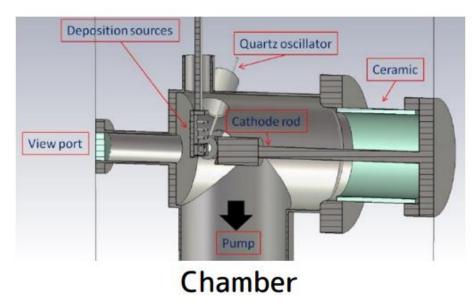
# Improving lifetimes of NEA surfaces

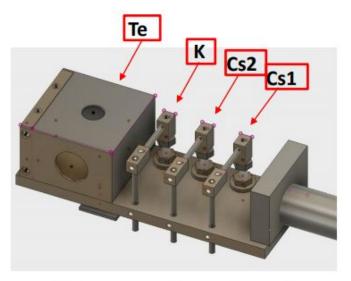
Improving robustness of cathode would:

- Ease the vacuum requirements
- Possibly allow for use of RF electron gun
- Improve intensity, bunch length, emittance

HU working on a better NEA surface to produce the above improvements: Cs-K-Te shows promise as a candidate cathode.

# **NEA Production Apparatus**

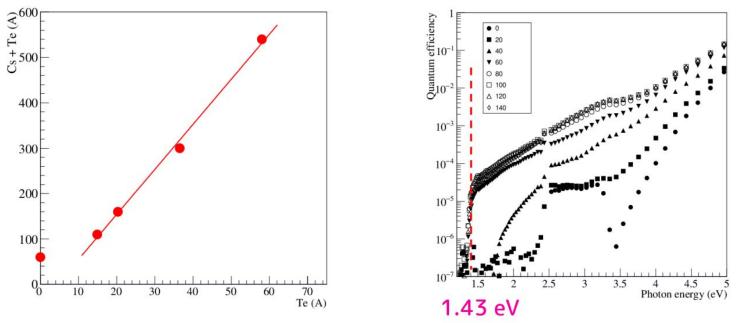




#### **Evaporation head**

- Chemically polished SUS chamber with NEA and ion pumps
  - Vacuum pressure ~1.5 x 10<sup>-8</sup> Pa
- Quartz thickness monitor
- QE measurement taken with Xe lamp

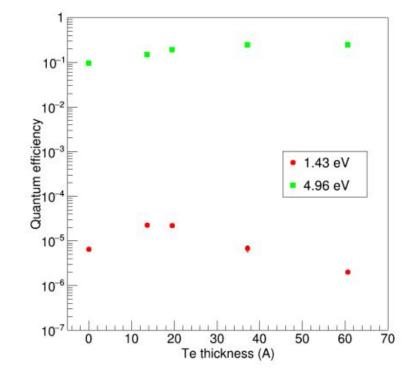
## **Optimal NEA Thickness Evaluation**

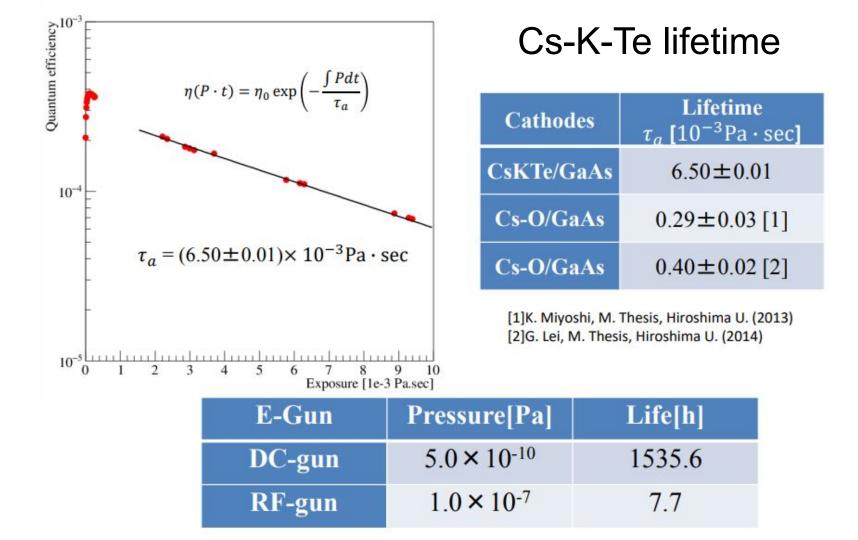


- Evaporate Te onto GaAs substrate to desired thickness
- Evaporate K and Cs repeatedly
- Measure QE spectrum after each K/Cs evaporation
- Optimum thickness is defined at that which has the maximum QE at 4.9 eV.

# **Optimal NEA Thickness Evaluation**

- QE at 4.96 eV is saturated with Te thickness
- QE at 1.43 eV peaks at ~15-20 Å
- Consistent with electron emission with 4.96 and
  1.43 photons from Cs-K-Te and GaAs, respectively.





# Conclusion

- HU working on producing polarized electron sources
  - GaAs source can provide > 90% polarized electrons with
- Utilizing NEA film to improve emitted beam
- Cs-K-Te surface on a GaAs substrate looks like a promising candidate
  - Longer lifetime then previous Cs-O film
  - May be able to use RF gun (although this may require significant work)
- Optimal Te thickness is around 15-20 Å
  - $\circ$   $\,$  QE found to be 2.0 3.0 x 10^{-4} at this level
  - More Te reduces QE, while GaAs emission is saturated.

#### **Future Note**

On Monday, I submitted an abstract to the Japanese Particle Accelerator Society yearly meeting (to be held virtually in September).

Title: Development of a Polarized Beam for SuperKEKB

I made the title general to allow for discussion of the full polarized beam development, so input will be appreciated.

Abstract (JP):

茨城県つくば市の SuperKEKBコライダーは2016年から電子・陽電子を Belle II実験へ送り、2018年から衝突させています。それ以来ビー ム電流を上げ、両ビームを「ナノビーム」まで搾り、前世代加速器であった KEKBの瞬間ルミノシティの40倍、蓄積したデータの50倍を目指し ています。その他には、将来 SuperKEKBの技術を高めたり、Belle IIの物理プログラムを更に広げるため、偏極電子ビームを開発する可能性 を探っています。この発表は SuperKEKBにおける偏極電子ビームの企画やチャレンジ、及び新たに開ける可能性について説明します。